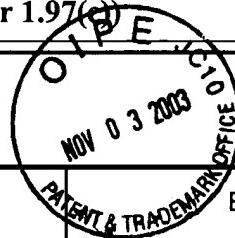


TRANSMITTAL OF INFORMATION DISCLOSURE STATEMENT
(Under 37 CFR 1.97(b) or 1.97(c))

Docket No.
SETI-0006

In Re Application Of: Fareed et al.



Serial No.	Filing Date	Examiner	Group Art Unit
10/659,183	September 10, 2003	Unknown	Unknown

Title: HETEROSTRUCTURE SEMICONDUCTOR DEVICE

Address to:

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

37 CFR 1.97(b)

1. The Information Disclosure Statement submitted herewith is being filed within three months of the filing of a national application other than a continued prosecution application under 37 CFR 1.53(d); within three months of the date of entry of the national stage as set forth in 37 CFR 1.491 in an international application; before the mailing of a first Office Action on the merits, or before the mailing of a first Office Action after the filing of a request for continued examination under 37 CFR 1.114.

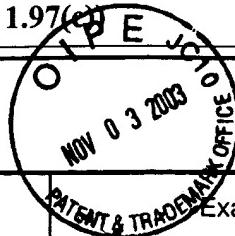
37 CFR 1.97(c)

2. The Information Disclosure Statement submitted herewith is being filed after the period specified in 37 CFR 1.97(b), provided that the Information Disclosure Statement is filed before the mailing date of a Final Action under 37 CFR 1.113, a Notice of Allowance under 37 CFR 1.311, or an Action that otherwise closes prosecution in the application, and is accompanied by one of:
 - the statement specified in 37 CFR 1.97(e);
 - OR**
 - the fee set forth in 37 CFR 1.17(p).

TRANSMITTAL OF INFORMATION DISCLOSURE STATEMENT
(Under 37 CFR 1.97(b) or 1.97(c))

Docket No.
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Serial No.

10/659,183

Filing Date

September 10, 2003

PATENT & TRADEMARK EXAMINER

Unknown

Group Art Unit

Unknown

HETEROSTRUCTURE SEMICONDUCTOR DEVICE

Payment of Fee

(Only complete if Applicant elects to pay the fee set forth in 37 CFR 1.17(p))

- A check in the amount of _____ is attached.
- The Director is hereby authorized to charge and credit Deposit Account No. 500999 as described below.
- Charge the amount of _____
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Dorothea Rubbone

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Dorothea Rubbone

Typed or Printed Name of Person Mailing Certificate

*This certificate may only be used if paying by deposit account.

John W. LaBatt

Signature

Dated: October 30, 2003

John W. LaBatt

Reg. No. 48,301

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INFORMATION DISCLOSURE CITATION

(Use several sheets if necessary)

Docket Number (Optional)
SETI-0006

Application Number
10/659,183

Applicant(s)
Fareed et al.

Filing Date
September 10, 2003

Group Art Unit
Unknown

*EXAMINER
INITIAL

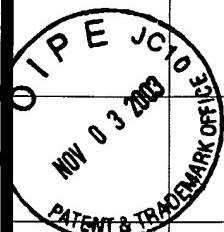
OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

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"Current/Voltage Characteristic Collapse in AlGaN/GaN Heterostructure Insulated Gate Field Effect Transistors at High Drain Bias," M. A. Khan et al., Electronic Letters, Vol. 30, No. 25, December 8, 1994, pp. 2175-2176.



EXAMINER

DATE CONSIDERED

*EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.